

IN THE UNITED STATES PATENT OFFICE

In Re Patent Application of

First Named Inventor: Garrett, Jr., Billy

Application No.: 09/837,307

Filed: 4/17/2001

For: MECHANISM FOR ENABLING FULL DATA
BUS UTILIZATION WITHOUT INCREASING
DATA GRANULARITY

Examiner: Dinh, Ngoc V.

Art Unit: 2187

Confirmation 9703
No.:

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. 1.97

Sir:

Enclosed is an Information Disclosure Citation Form 1449/PTO together with a copy of each reference cited therein, excluding U.S. Patents and Published U.S. Patent Applications. It is respectfully requested that the cited references be considered and that the enclosed copy of the Form 1449/PTO be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant.

This Information Disclosure Statement is being submitted under one of the following (as indicated by an "X" to the left of the appropriate paragraph):

_____ 37 C.F.R. §1.97(b).

 X 37 C.F.R. §1.97(c).

 X Authorization is hereby given to charge Deposit Account No. 501914 for the fee of \$180.00 under 37 C.F.R. §1.17(p) for the submission of this Information Disclosure Statement; or

_____ A statement pursuant to 37 C.F.R. §1.97(e) is attached hereto.

_____ 37 C.F.R. §1.97(d). Authorization is hereby given to charge Deposit Account No. 501914 for the fee of \$180.00 and a statement pursuant to 37 C.F.R. §1.97(e) is enclosed.

Pursuant to 37 C.F.R.1.97(h), the submission of this Information Disclosure Statement is not to be construed as an admission that the information cited in this statement is material to patentability.

The Commissioner is hereby authorized to charge any fee deficiency in connection with this submission to Deposit Account No. 501914.

Respectfully submitted,

SHEMWELL MAHAMEDI LLP

Date January 25, 2007



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Tel. 408-236-6640

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STATEMENT BY APPLICANT**

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Examiner	Dinh, Ngoc V.
Atty. Docket No.	RBS2.P031

U.S. Patent Documents

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Considered**

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